

TERMINAL ASSIGNMENT

CMOS Hex Voltage-Level Shifter for TTL-to-CMOS or CMOS-to-CMOS Operation

High-Voltage Types (20-Volt Rating)

Features:

- Independence of power-supply sequence considerations— V_{CC} can exceed V_{DD} ; input signals can exceed both V_{CC} and V_{DD}
- Up and down level-shifting capability
- Shiftable input threshold for either CMOS or TTL compatibility
- Standardized symmetrical output characteristics
- 100% tested for quiescent current @ 20 V
- Maximum input current of 1 μ A at 18 V over full package-temperature range; 100 nA at 18 V and 25°C
- 5 V, 10 V, and 15 V parametric ratings
- Meets all requirements of JEDEC Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"

■ CD4504B hex voltage level-shifter consists of six circuits which shift input signals from the V_{CC} logic level to the V_{DD} logic level. To shift TTL signals to CMOS logic levels, the SELECT input is at the V_{CC} HIGH logic state. When the SELECT input is at a LOW logic state, each circuit translates signals from one CMOS level to another.

The CD4504B types are supplied in 16-lead hermetic dual-in-line ceramic packages (F3A suffix), 16-lead dual-in-line plastic packages (E suffix), 16-lead small-outline packages (M, M96, and MT suffixes), and 16-lead thin shrink small-outline packages (PW and PWR suffixes).

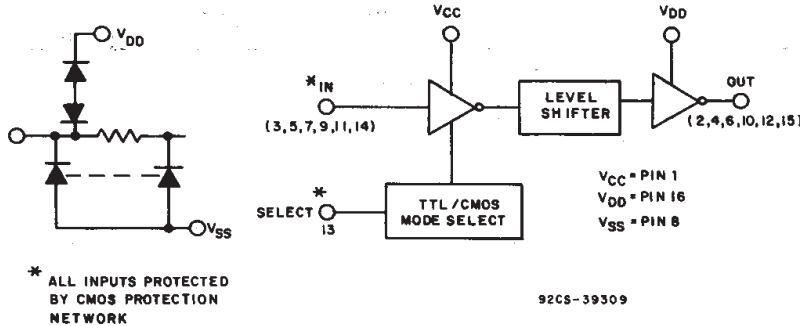


Fig. 1 - Functional diagram for CD4504B.

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY-VOLTAGE RANGE, (V_{DD})	
Voltages referenced to V_{SS} Terminal	-0.5V to +20V
INPUT VOLTAGE RANGE, ALL INPUTS	
	-0.5V to V_{CC} +0.5V
DC INPUT CURRENT, ANY ONE INPUT	
	\pm 10mA
POWER DISSIPATION PER PACKAGE (P_D):	
For $T_A = -55^\circ\text{C}$ to $+100^\circ\text{C}$	500mW
For $T_A = +100^\circ\text{C}$ to $+125^\circ\text{C}$:	Derate Linearly at 12mW/ $^\circ\text{C}$ to 200mW
DEVICE DISSIPATION PER OUTPUT TRANSISTOR -	
FOR $T_A =$ FULL PACKAGE-TEMPERATURE RANGE (All Package Types)	100mW
OPERATING-TEMPERATURE RANGE (T_A)	
	-55°C to $+125^\circ\text{C}$
STORAGE TEMPERATURE RANGE (T_{stg})	
	-85°C to $+150^\circ\text{C}$
LEAD TEMPERATURE (DURING SOLDERING):	
At distance 1/16 \pm 1/32 inch (1.59 \pm 0.79mm) from case for 10s max	+265°C

3
COMMERCIAL CMOS
HIGH VOLTAGE ICs

CD4504B Types

V_{GEN}

STATIC ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	CONDITIONS				LIMITS AT INDICATED TEMPERATURES (°C)							UNITS	
	V _O (V)	V _{IN} (V)	V _{CC} (V)	V _{DD} (V)	-55	-40	+85	+125	+25				
									MIN	TYP	MAX		
Quiescent Device Current, I _{DD} Max and I _{CC} in CMOS-CMOS Mode	—	0,5	5	5	1.5	1.5	1.5	1.5	—	0.02	1.5	mA	
	—	0,10	5	10	2	2	2	2	—	0.02	2		
	—	0,15	5	15	4	4	120	120	—	0.02	4	μA	
	—	0,20	5	20	20	20	600	600	—	0.04	20		
Quiescent Device Current, I _{CC} Max TTL-CMOS Mode	—	0,5	5	5	5	5	6	6	—	2.5	5	mA	
	—	0,10	5	10	5	5	6	6	—	2.5	5		
	—	0,15	5	15	5	5	6	6	—	2.5	5		
Output Low (Sink) Current, I _{OL} Min	0.4	0.5	—	5	0.64	0.61	0.42	0.36	0.51	1	—	mA	
	0.5	0,10	—	10	1.6	1.5	1.1	0.9	1.3	2.6	—		
	1.5	0,15	—	15	4.2	4	2.8	2.4	3.4	6.8	—		
Output High (Source) Current, I _{OH} Min	4.6	0,5	—	5	-0.64	-0.61	-0.42	-0.36	-0.51	-1	—	mA	
	2.5	0,5	—	5	-2	-1.8	-1.3	-1.15	-1.6	-3.2	—		
	9.5	0,10	—	10	-1.6	-1.5	-1.1	-0.9	-1.3	-2.6	—		
	13.5	0,15	—	15	-4.2	-4	-2.8	-2.4	-3.4	-6.8	—		
Output Voltage: Low-Level, V _{OL} Max	—	0,5	—	5	0.05				—	0	0.05	V	
	—	0,10	—	10	0.05				—	0	0.05		
	—	0,15	—	15	0.05				—	0	0.05		
Output Voltage: High-Level, V _{OH} Min	—	0,5	—	5	4.95				4.95	5	—	V	
	—	0,10	—	10	9.95				9.95	10	—		
	—	0,15	—	15	14.95				14.95	15	—		
Input Low Voltage, V _{IL} Max Note 1	TTL-CMOS	1	—	5	10	0.8				—	—	0.8	V
	TTL-CMOS	1	—	5	15	0.8				—	—	0.8	
	CMOS-CMOS	1	—	5	10	1.5				—	—	1.5	
	CMOS-CMOS	1.5	—	5	15	1.5				—	—	1.5	
	CMOS-CMOS	1.5	—	10	15	3				—	—	3	
Input High Voltage, V _{IH} Min Note 1	TTL-CMOS	9	—	5	10	2				2	—	—	V
	TTL-CMOS	13.5	—	5	15	2				2	—	—	
	CMOS-CMOS	9	—	5	10	3.5				3.5	—	—	
	CMOS-CMOS	13.5	—	5	15	3.5				3.5	—	—	
	CMOS-CMOS	13.5	—	10	15	7				7	—	—	
Input Current, I _{IN} Max	—	0,18	—	18	±0.1	±0.1	±1	±1	—	±10 ⁻⁵	±0.1	μA	

Note 1: Applies to the 6 input signals. For mode control (P13), only the CMOS-CMOS ratings apply.

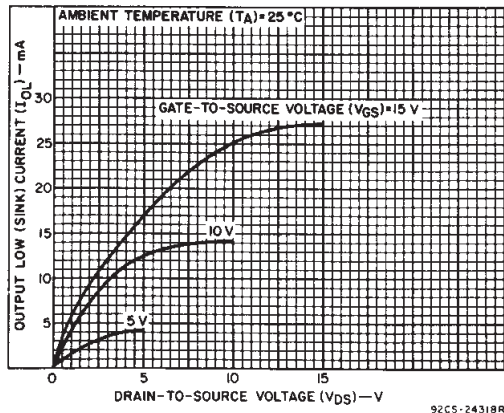


Fig. 2 - Typical output low (sink) current characteristics.

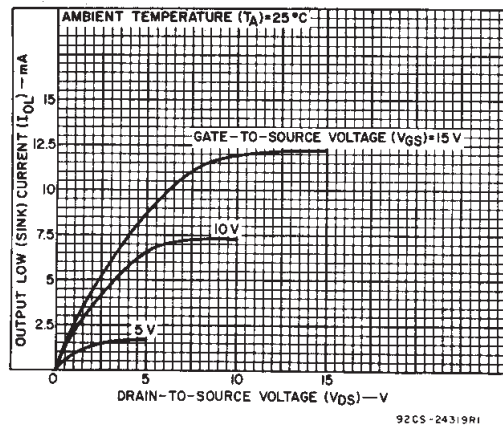
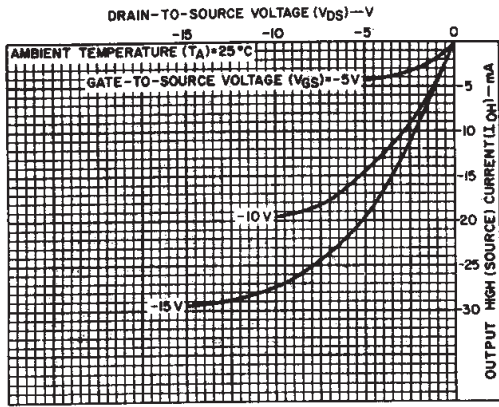


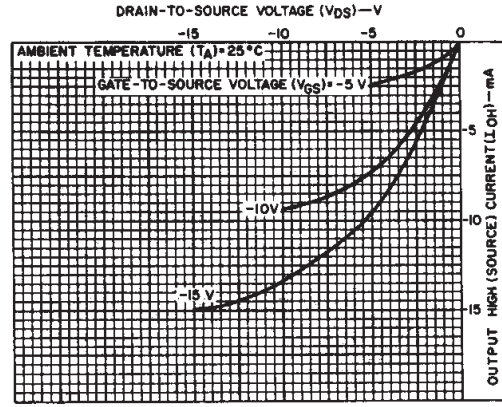
Fig. 3 - Minimum output low (sink) current characteristics.

CD4504B Types



92CS-24320R3

Fig. 4 - Typical output high (source) current characteristics.



92CS-24321R2

Fig. 5 - Minimum output high (source) current characteristics.

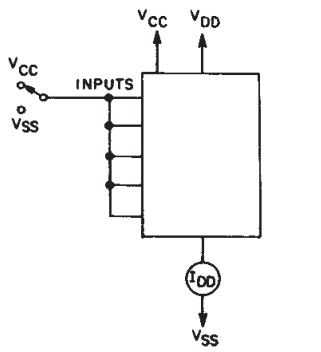
RECOMMENDED OPERATING CONDITIONS

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC	V _{DD} (V)	LIMITS		UNITS
		Min.	Max.	
Supply-Voltage Range (For T _A = Full Package-Temperature Range)	—	5	18	V

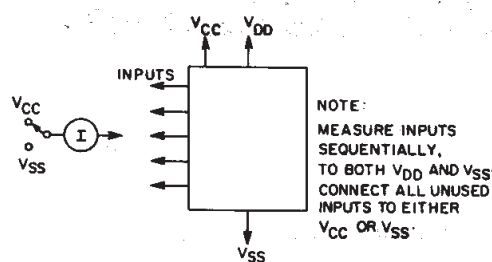
DYNAMIC ELECTRICAL CHARACTERISTICS, At T_A = 25°C; Input t_r, t_f = 20 ns, C_L = 50 pF, R_L = 200 Ω

CHARACTERISTIC	SHIFTING MODE	V _{CC} (V)	V _{DD} (V)	LIMITS		UNITS
				TYP.	MAX.	
Propagation Delay: High-to-Low, t _{PHL}	TTL to CMOS V _{DD} > V _{CC}	5	10	140	280	ns
	CMOS to CMOS V _{DD} > V _{CC}	5	15	140	280	
	CMOS to CMOS V _{CC} > V _{DD}	5	10	120	240	
	CMOS to CMOS V _{CC} > V _{DD}	5	15	120	240	
	CMOS to CMOS V _{CC} > V _{DD}	10	5	275	550	
	CMOS to CMOS V _{CC} > V _{DD}	15	5	275	550	
	CMOS to CMOS V _{CC} > V _{DD}	10	15	70	140	
	CMOS to CMOS V _{CC} > V _{DD}	15	10	70	140	
Low-to-High, t _{PLH}	TTL to CMOS V _{DD} > V _{CC}	5	10	140	280	ns
	CMOS to CMOS V _{DD} > V _{CC}	5	15	140	280	
	CMOS to CMOS V _{CC} > V _{DD}	5	10	120	240	
	CMOS to CMOS V _{CC} > V _{DD}	5	15	120	240	
	CMOS to CMOS V _{CC} > V _{DD}	10	5	200	400	
	CMOS to CMOS V _{CC} > V _{DD}	15	5	200	400	
	CMOS to CMOS V _{CC} > V _{DD}	10	15	60	120	
	CMOS to CMOS V _{CC} > V _{DD}	15	10	60	120	
Transition Time, t _{THL} , t _{TLH}	All Modes		5	100	200	ns
	All Modes		10	50	100	
	All Modes		15	40	80	
Input Capacitance, C _{IN}	Any Input			5	7.5	pF



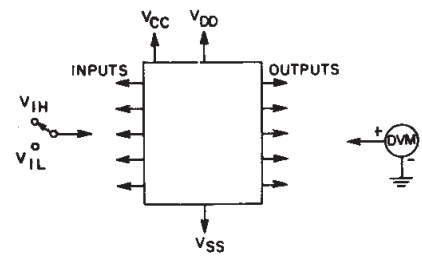
92CS-29452

Fig. 6 - Quiescent device current.



92CS-29454

Fig. 7 - Input current.



NOTE:
TEST ANY COMBINATION
OF INPUTS

92CS-29453

Fig. 8 - Input voltage.

3
COMMERCIAL CMOS
HIGH VOLTAGE ICs

CD4504B Types

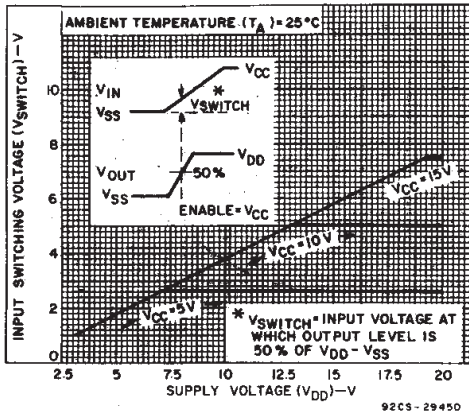


Fig. 9 - Typical input switching as a function of high-level supply voltage. (SELECT at V_{CC} -CMOS mode).

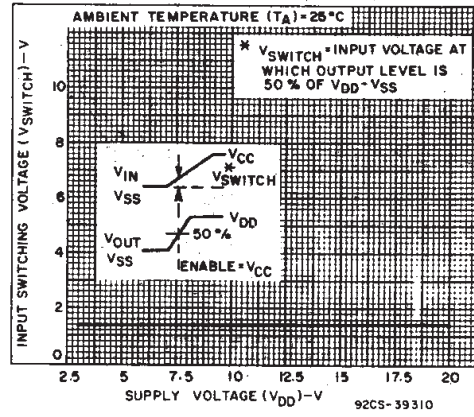


Fig. 10 - Typical input switching as a function of high-level supply voltage (SELECT at V_{SS} -TTL mode).

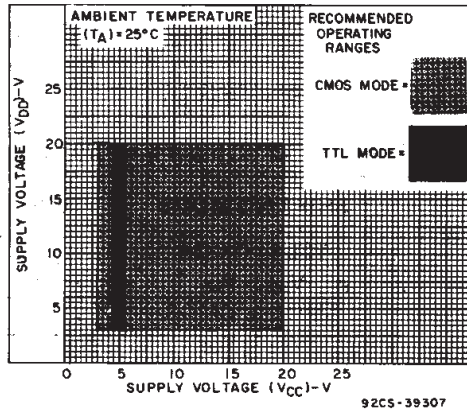
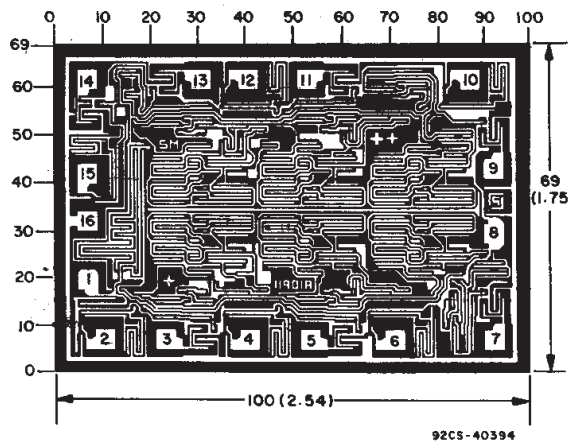


Fig. 11 - High-level supply voltage vs. low-level supply voltage.



Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch).

Dimensions and pad layout for CD4504BH.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
CD4504BE	Active	Production	PDIP (N) 16	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD4504BE
CD4504BE.A	Active	Production	PDIP (N) 16	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD4504BE
CD4504BEE4	Active	Production	PDIP (N) 16	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD4504BE
CD4504BF3A	Active	Production	CDIP (J) 16	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	CD4504BF3A
CD4504BF3A.A	Active	Production	CDIP (J) 16	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	CD4504BF3A
CD4504BM	Active	Production	SOIC (D) 16	40 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4504BM
CD4504BM.A	Active	Production	SOIC (D) 16	40 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4504BM
CD4504BM96	Active	Production	SOIC (D) 16	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4504BM
CD4504BM96.A	Active	Production	SOIC (D) 16	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4504BM
CD4504BM96E4	Active	Production	SOIC (D) 16	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4504BM
CD4504BME4	Active	Production	SOIC (D) 16	40 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4504BM
CD4504BMG4	Active	Production	SOIC (D) 16	40 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4504BM
CD4504BMT	Active	Production	SOIC (D) 16	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4504BM
CD4504BMT.A	Active	Production	SOIC (D) 16	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4504BM
CD4504BPW	Active	Production	TSSOP (PW) 16	90 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM504B
CD4504BPW.A	Active	Production	TSSOP (PW) 16	90 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM504B
CD4504BPWE4	Active	Production	TSSOP (PW) 16	90 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM504B
CD4504BPWR	Active	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	-55 to 125	CM504B
CD4504BPWR.A	Active	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM504B

(1) **Status:** For more details on status, see our [product life cycle](#).

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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OTHER QUALIFIED VERSIONS OF CD4504B, CD4504B-MIL :

- Catalog : [CD4504B](#)
- Enhanced Product : [CD4504B-EP](#), [CD4504B-EP](#)
- Military : [CD4504B-MIL](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product
- Enhanced Product - Supports Defense, Aerospace and Medical Applications
- Military - QML certified for Military and Defense Applications

TAPE AND REEL INFORMATION

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

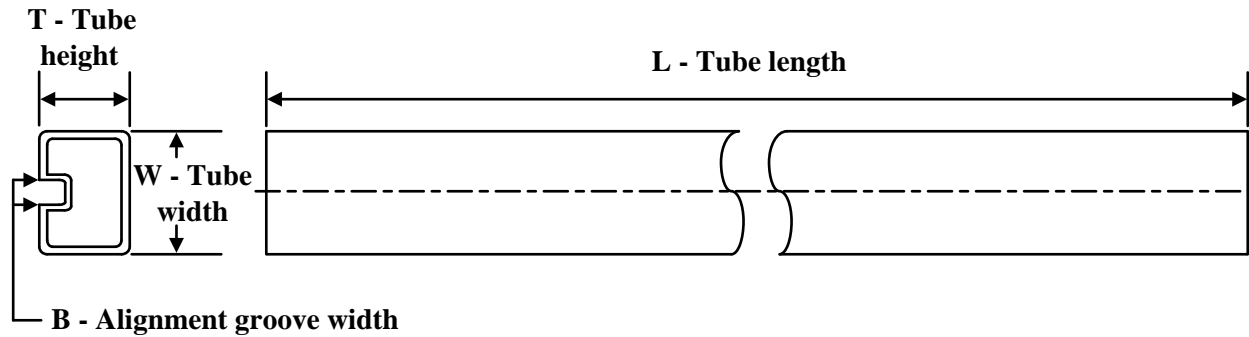

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD4504BM96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD4504BPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD4504BM96	SOIC	D	16	2500	353.0	353.0	32.0
CD4504BPWR	TSSOP	PW	16	2000	353.0	353.0	32.0

TUBE


*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
CD4504BE	N	PDIP	16	25	506	13.97	11230	4.32
CD4504BE	N	PDIP	16	25	506	13.97	11230	4.32
CD4504BE.A	N	PDIP	16	25	506	13.97	11230	4.32
CD4504BE.A	N	PDIP	16	25	506	13.97	11230	4.32
CD4504BEE4	N	PDIP	16	25	506	13.97	11230	4.32
CD4504BEE4	N	PDIP	16	25	506	13.97	11230	4.32
CD4504BM	D	SOIC	16	40	507	8	3940	4.32
CD4504BM.A	D	SOIC	16	40	507	8	3940	4.32
CD4504BME4	D	SOIC	16	40	507	8	3940	4.32
CD4504BMG4	D	SOIC	16	40	507	8	3940	4.32
CD4504BPW	PW	TSSOP	16	90	530	10.2	3600	3.5
CD4504BPW.A	PW	TSSOP	16	90	530	10.2	3600	3.5
CD4504BPWE4	PW	TSSOP	16	90	530	10.2	3600	3.5

J (R-GDIP-T**)

14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE

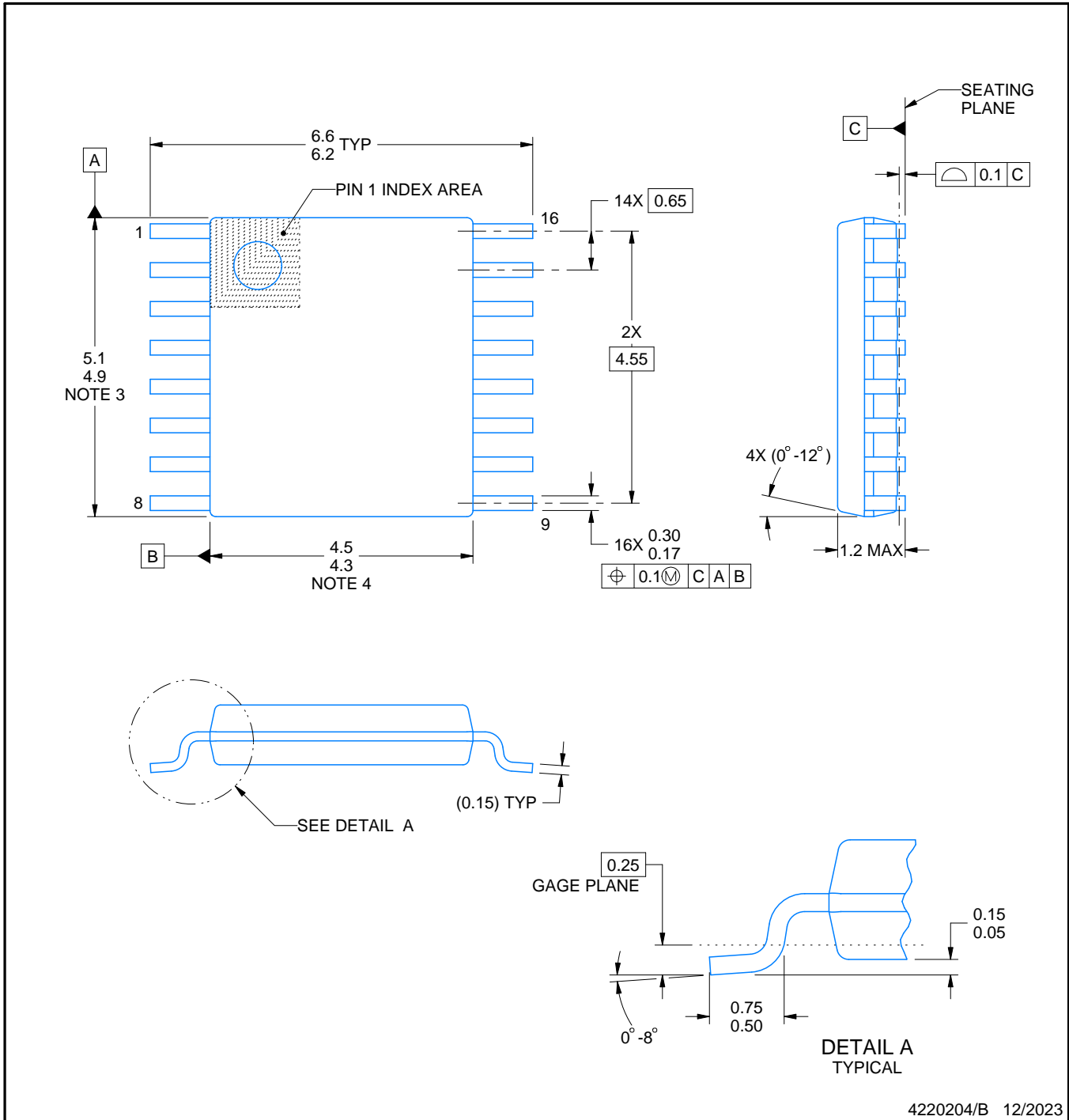


DIM \ PINS **	14	16	18	20
A	0.300 (7,62) BSC	0.300 (7,62) BSC	0.300 (7,62) BSC	0.300 (7,62) BSC
B MAX	0.785 (19,94)	.840 (21,34)	0.960 (24,38)	1.060 (26,92)
B MIN	—	—	—	—
C MAX	0.300 (7,62)	0.300 (7,62)	0.310 (7,87)	0.300 (7,62)
C MIN	0.245 (6,22)	0.245 (6,22)	0.220 (5,59)	0.245 (6,22)



4040083/F 03/03

- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. This package is hermetically sealed with a ceramic lid using glass frit.
 - D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
 - E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.



4220204/B 12/2023

NOTES:

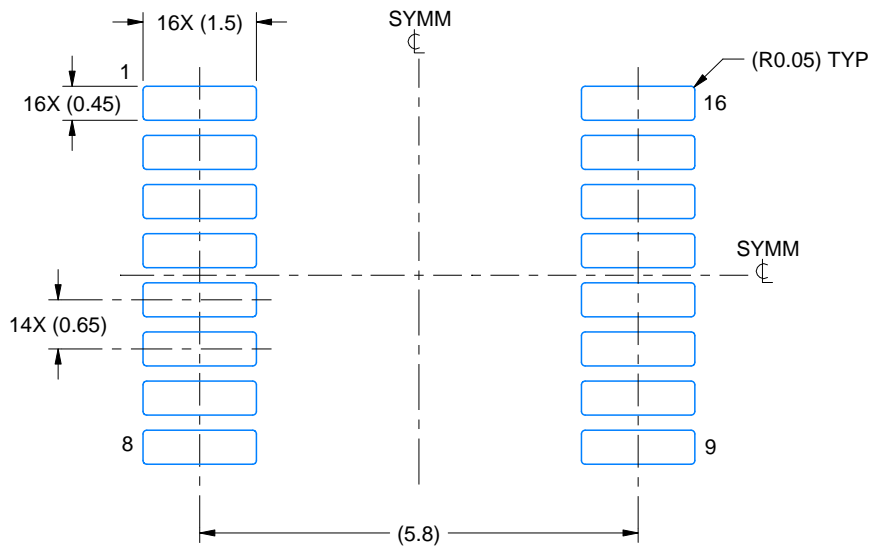
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.

EXAMPLE BOARD LAYOUT

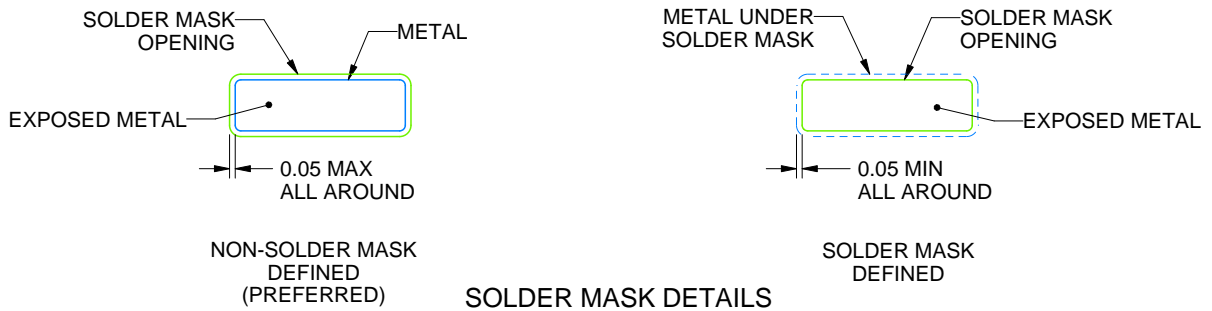
PW0016A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X



SOLDER MASK DETAILS

4220204/B 12/2023

NOTES: (continued)

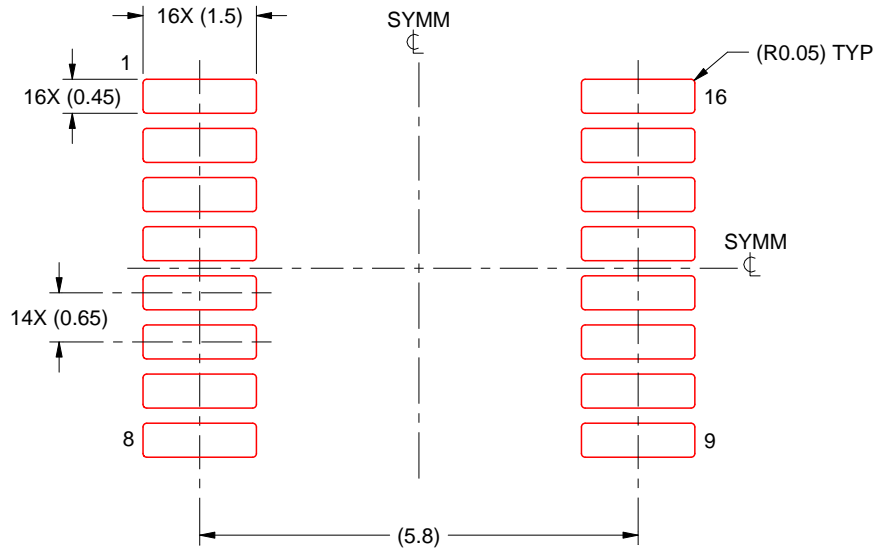
- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

PW0016A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220204/B 12/2023

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
 - The 20 pin end lead shoulder width is a vendor option, either half or full width.

D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
 - D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
 - E. Reference JEDEC MS-012 variation AC.

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